

**SUPPLEMENTAL REISSUE APPLICATION  
DECLARATION BY THE INVENTOR**

Docket Number  
198786US-2 RE

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original first and joint inventor (if plural names are listed below) of the subject matter which is described and claimed in the below identified patent:

Patent Number

5,945,692

Date Patent Issued

August 31, 1999

Title of Invention

SEMICONDUCTOR DEVICE AND METHOD OF FABRICATING SAME

for which a reissue patent is sought on the invention entitled:

SEMICONDUCTOR DEVICE AND METHOD OF FABRICATING SAME

the specification of which

☐ is attached hereto

☒ was filed on June 27, 2001 as reissue application number 09/891,925

☐ and (if applicable) was amended on

I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information which is material to patentability as defined in 37 CFR 1.56.

We (I) hereby claim foreign priority benefits under 35 USC §119(a)-(d) or §365(b) of any foreign application(s) for patent or inventor's certificate, or §365(a) of any PCT International application which designated at least one country other than the United States, listed below and have also identified below any foreign application for patent or inventor's certificate, or PCT international application having a filing date before that of the application on which priority is claimed. Prior Foreign Application(s):

Application No.

6-118386

Country

JAPAN

Day/Month/Year

31/May/1994

Priority Claimed

YES

We (I) hereby claim the benefit under 35 USC §119(e) of any United States *provisional* application(s) listed below.

Application Number

Filing Date

We (I) hereby claim the benefit under 35 USC §120 of any United States application(s), or §365I of any PCT International application designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States or PCT International application in the manner provided by the first paragraph of 35 USC §112, I acknowledge the duty to disclose information which is material to patentability as defined in 37 CFR §1.56 which became available between the filing date of the prior application and the national or PCT International filing date of this application.

Application Serial No.

Filing Date

Status

I verily believe the original patent to be wholly or partly inoperative or invalid, for the reasons described below. (Check all that apply)

☐ by reason of a defective specification or drawing.

☒ by reason of the patentee claiming more or less than he had the right to claim in the patent.

☐ by reason of other errors.

At least one error upon which reissue is based is described as follows:

Every error in the patent was which corrected in the present reissue application that is not covered by a prior oath/declaration submitted in the application, arose without any deceptive intention on the part of the applicant.

All errors corrected in this reissue application arose without any deceptive intention on the part of the applicant.

Reissue Application Declaration by the Inventor (Continued)

As a named inventor, I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected herewith:

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I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine and imprisonment, or both, under 18 U.S.C. 1001, and that such willful false statements may jeopardize the validity of the application, any patent issuing thereon, or any patent to which this declaration is directed.

Full Name of sole or first inventor (given name, family name)

Mitsuhiro YANO

Signature

Mitsuhiro Yano

Date

May 14, 2010

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Kouichi MOCHIZUKI

Signature

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Full Name of third joint inventor (given name, family name)

Signature

Date

Residence

Citizenship

Post Office Address

☐ Additional joint inventors are named on separately numbered sheets attached hereto.

(OSMMN 03/02)